

T16M35T600B(LS)

Triacs Silicon Bidirectional Thyristors

TRIACS 16 AMPERES RMS 600 VOLTS

FEATURES

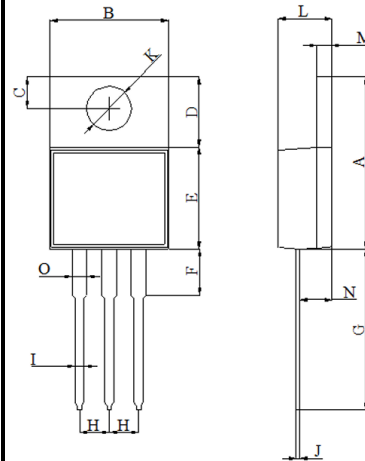
- Blocking voltage to 600V
- Minimizes Snubber Networks for Protection
- On-State Current Rating of 16 Amperes RMS High surge Current Capability - 150 Amperes
- Glass Passivated Junctions for Reliability and Uniformity Operational in Three Quadrants, Q1, Q2, and Q3
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](https://www.diodes.com/quality/product-definitions/) or your local Diodes representative.**

<https://www.diodes.com/quality/product-definitions/>

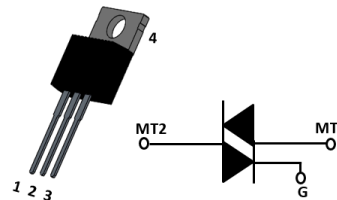
MECHANICAL DATA

- Package: TO-220AB
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Terminals: Finish – Tin Plated Leads, Solderable per MIL-STD-202, Method 208 Ⓔ3
- Weight: 0.07 ounces, 2.0 grams (Approximate)

TO-220AB



TO-220AB		
DIM.	MIN.	MAX.
A	14.40	15.20
B	9.65	10.67
C	2.54	3.43
D	5.84	6.86
E	8.26	9.28
F	-	4.20
G	12.70	14.73
H	2.29	2.79
I	0.51	1.14
J	0.30	0.64
K	3.53Ø	4.09Ø
L	3.56	4.83
M	1.14	1.40
N	2.03	2.92
O	1.14	1.70
All Dimensions in millimeter		



PIN ASSIGNMENT	
1	Main terminal 1
2	Main terminal 2
3	Gate
4	Main terminal 2

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at +25°C ambient temperature unless otherwise specified.

MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Peak repetitive off-state voltage ($T_J = -40$ to $+125^\circ\text{C}$, sine wave, 50 to 60Hz; gate open)	V_{DRM} V_{RRM}	600 600	Volts
On-stage RMS current (full sine wave 50 to 60Hz, $T_C = +80^\circ\text{C}$)	$I_{T(RMS)}$	16	Amp
Peak non-repetitive surge current (one full cycle 60Hz, $T_J = +25^\circ\text{C}$)	I_{TSM}	150	Amps
Circuit fusing consideration ($t = 8.3\text{ms}$)	I^2t	93	A^2s
Operating junction temperature range	T_J	-40 to +125	$^\circ\text{C}$
Storage temperature range	T_{STG}	-40 to +150	$^\circ\text{C}$

Notes:

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

OFF CHARACTERISTICS

PARAMETER		SYMBOL	MAX	UNIT
Peak repetitive forward or reverse blocking current (V_{AK} = rated V_{DRM} and V_{RRM} , gate open)	$T_J = +25^{\circ}\text{C}$	I_{DRM}	0.01	mA
	$T_J = +125^{\circ}\text{C}$	I_{RRM}	2.0	

ON CHARACTERISTICS

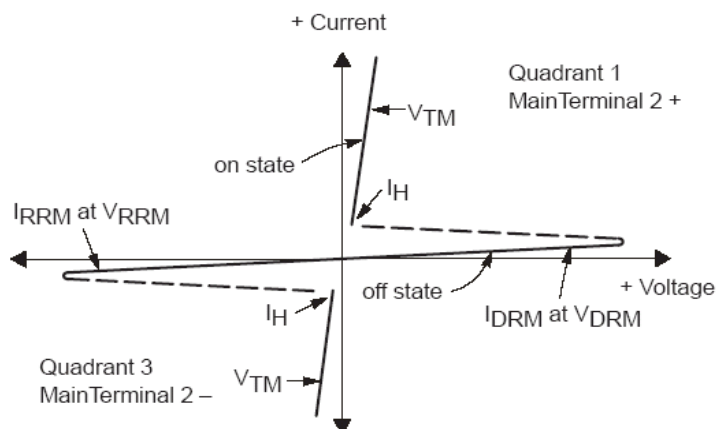
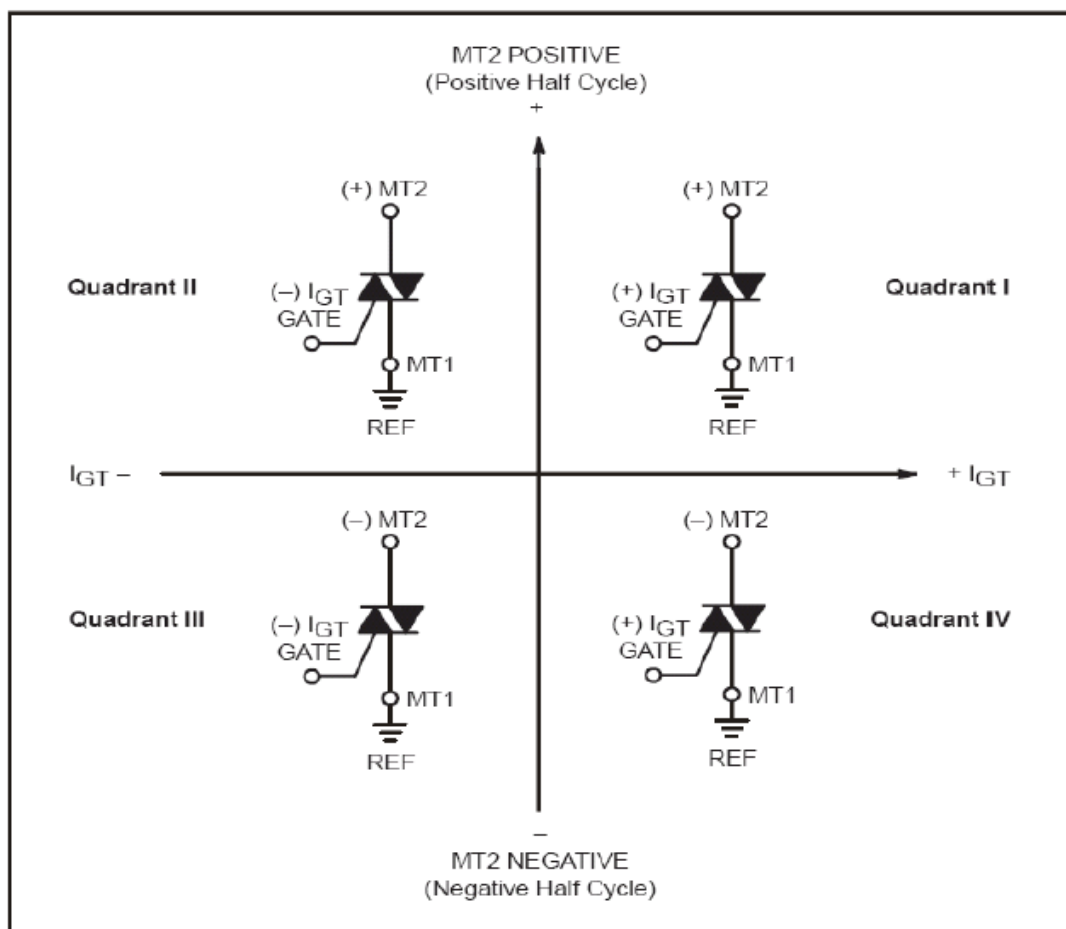
PARAMETER	SYMBOL	MAX	UNIT
Peak forward on-state voltage ($I_{TM} = \pm 16\text{A}$ @ $t_P \leq 2.0\text{ms}$, duty cycle $\leq 2\%$)	V_{TM}	1.6	Volts
Gate trigger current ($V_D = 12\text{V}$, $R_L = 100\Omega$)	I_{GT1} I_{GT2} I_{GT3}	35 35 35	mA
Gate trigger voltage ($V_D = 12\text{V}$, $R_L = 100\Omega$)	V_{GT1} V_{GT2} V_{GT3}	1.5 1.5 1.5	
Holding current ($V_D = 12\text{V}$, initiation current = $\pm 150\text{mA}$, gate open)	I_H	50	mA
Latching current ($V_D = 12\text{V}$, $I_G = 35\text{mA}$)	I_{L1} I_{L2} I_{L3}	50 80 50	mA

DYNAMIC CHARACTERISTICS

PARAMETER	SYMBOL	MIN	UNIT
Critical rate of rise of Commutation voltage $V_D = 67\%$ rated V_{DRM} , exponential waveform, $T_C = +125^{\circ}\text{C}$	dv/dt	600	V/ μs

RATING AND CHARACTERISTIC CURVES
T16M35T600B(LS)

Symbol	Parameter
V_{DRM}	Peak Repetitive Forward Off State Voltage
I_{DRM}	Peak Forward Blocking Current
V_{RRM}	Peak Repetitive Reverse Off State Voltage
I_{RRM}	Peak Reverse Blocking Current
V_{TM}	Maximum On State Voltage
I_H	Holding Current


Quadrant Definitions


All polarities are referenced to MT1

Whith in -phase signal (using standard AC lines) quadrants I and III are used

RATING AND CHARACTERISTIC CURVES
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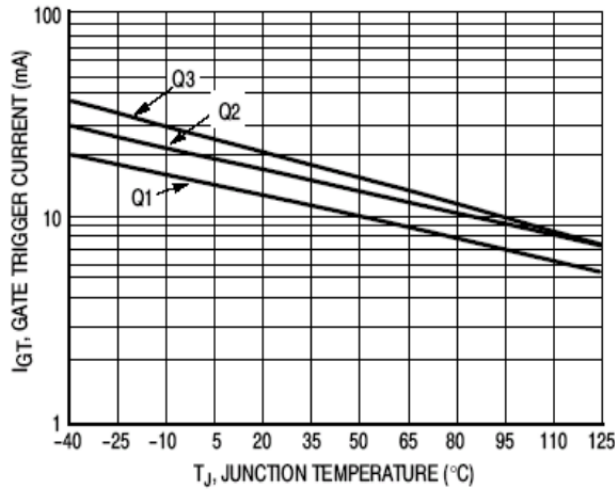


Figure 1. Typical Gate Trigger Current versus Junction Temperature

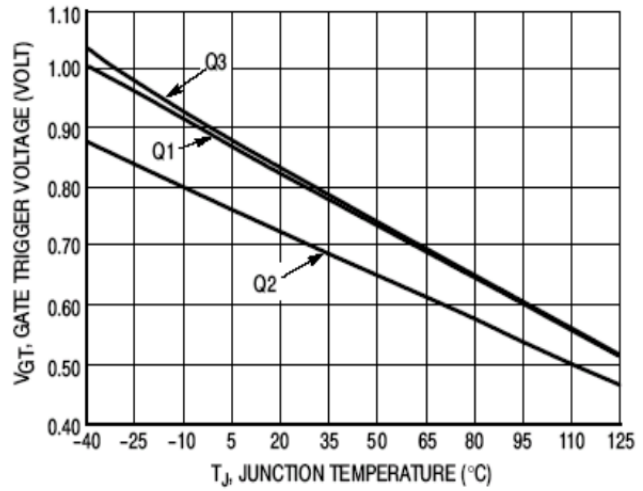


Figure 2. Typical Gate Trigger Voltage versus Junction Temperature

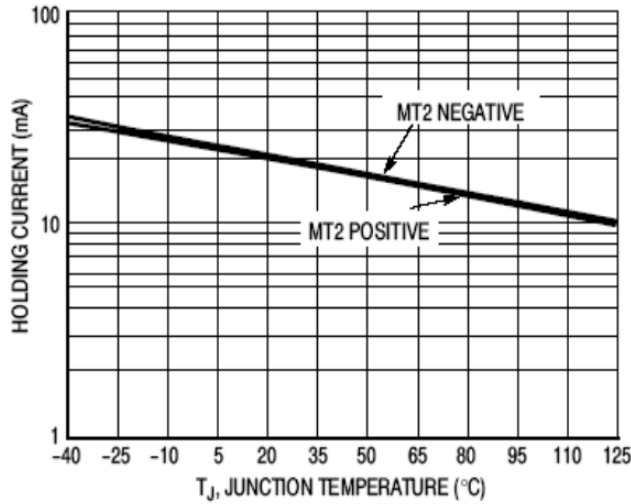


Figure 3. Typical Holding Current versus Junction Temperature

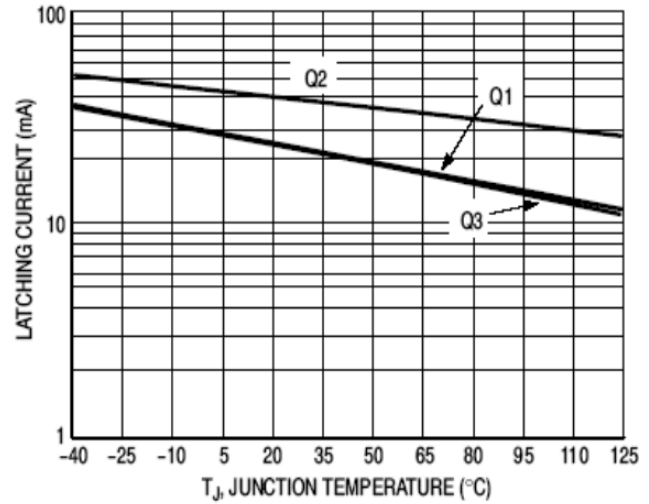


Figure 4. Typical Latching Current versus Junction Temperature

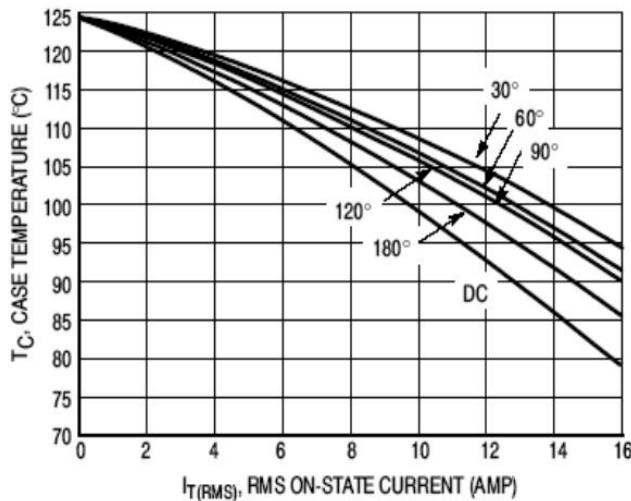


Figure 5. Typical RMS Current Derating

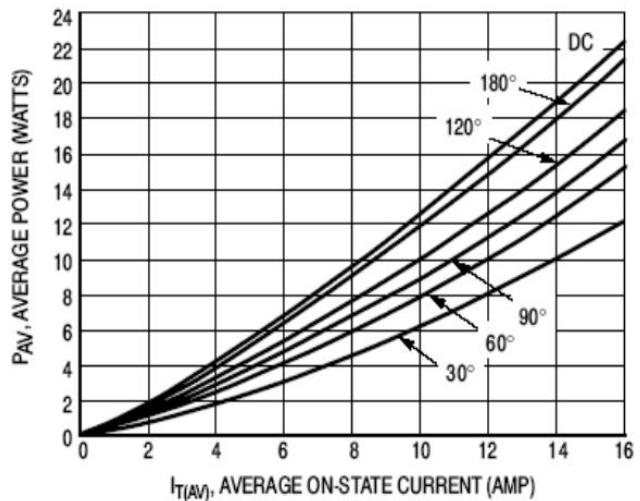


Figure 6. On-State Power Dissipation

RATING AND CHARACTERISTIC CURVES
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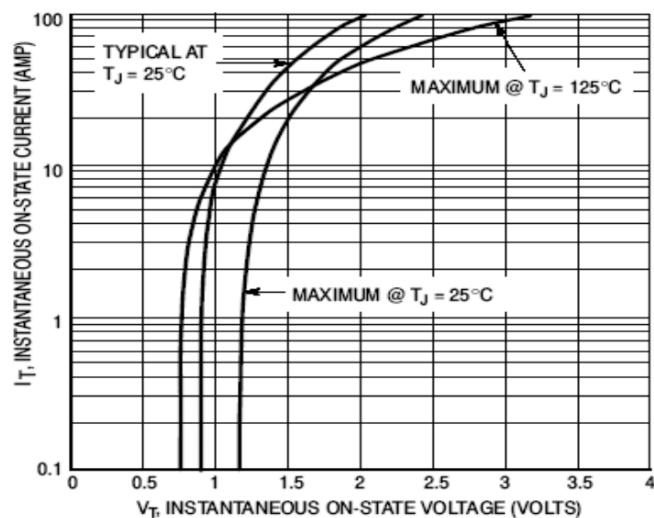


Figure 7. On-State Characteristics

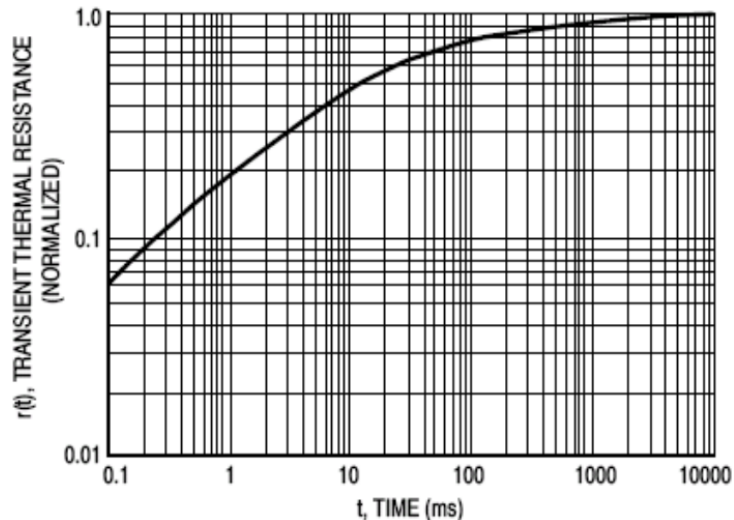
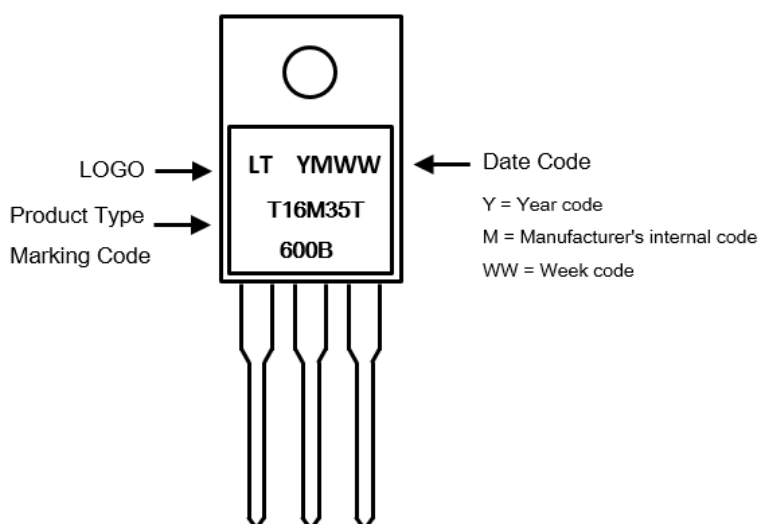


Figure 8. Typical Thermal Response

Ordering Information:

Orderable Part Number	Package	Packing	
		Qty.	Carrier
T16M35T600B	TO-220AB	50pcs	Tube

Marking Information:



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